MMBT5551LT1 is a Preferred Device

High Voltage Transistors NPN Silicon

Features

• Pb-Free Packages are Available

MAXIMUM RATINGS

Rating	Symbol	5550	5551	Unit
Collector – Emitter Voltage	V _{CEO}	140	160	Vdc
Collector-Base Voltage	Base Voltage V _{CBO} 160 180		Vdc	
Emitter-Base Voltage	V _{EBO}	6.0		Vdc
Collector Current – Continuous	Ι _C	600		mAdc

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^{\circ}C$	P _D	225	mW
Derate Above 25°C		1.8	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate (Note 2) $T_A = 25^{\circ}C$	PD	300	mW
Derate Above 25°C		2.4	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

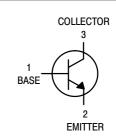
1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

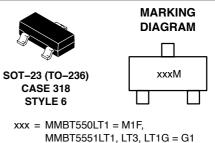
2. Alumina = 0.4 \times 0.3 \times 0.024 in. 99.5% alumina.



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http://onsemi.com





M = Month Code

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT5550LT1	SOT-23	3000 Tape & Reel
MMBT5550LT1G	SOT–23 (Pb–Free)	3000 Tape & Reel
MMBT5551LT1	SOT-23	3000 Tape & Reel
MMBT5551LT1G	SOT–23 (Pb–Free)	3000 Tape & Reel
MMBT5551LT3	SOT-23	10,000 Tape & Reel
MMBT5551LT3G	SOT–23 (Pb–Free)	10,000 Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications

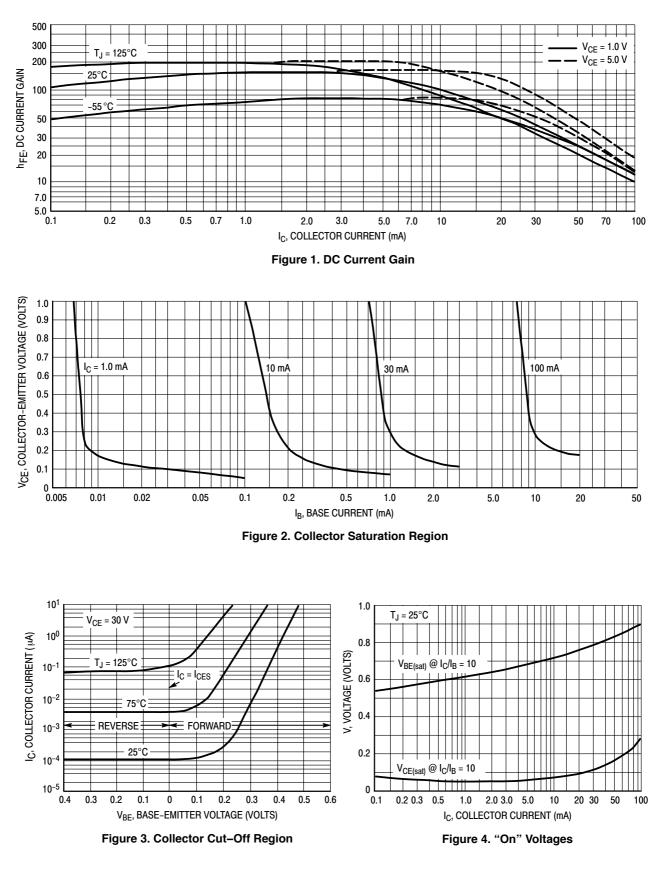
Brochure, BRD8011/D.

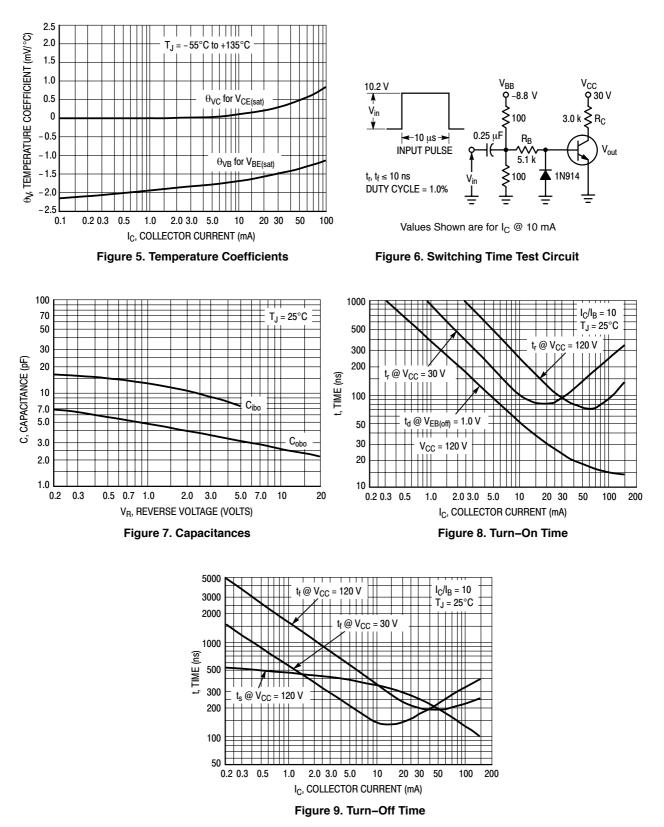
Preferred devices are recommended choices for future use and best overall value.

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (Note 3) $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	MMBT5550 MMBT5551	V _{(BR)CEO}	140 160		Vdc
Collector – Base Breakdown Voltage $(I_C = 100 \ \mu Adc, I_E = 0)$	MMBT5550 MMBT5551	V _{(BR)CBO}	160 180		Vdc
Emitter – Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$		V _{(BR)EBO}	6.0	_	Vdc
	MMBT5550 MMBT5551 MMBT5550 MMBT5551	I _{CBO}	- - -	100 50 100 50	nAdc μAdc
Emitter Cutoff Current ($V_{EB} = 4.0 \text{ Vdc}, I_C = 0$)		I _{EBO}	_	50	nAdc
ON CHARACTERISTICS					
DC Current Gain ($I_C = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$) ($I_C = 10 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$) ($I_C = 50 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$)	MMBT5550 MMBT5551 MMBT5550 MMBT5551 MMBT5550 MMBT5551	h _{FE}	60 80 60 80 20 30	- 250 250 - -	-
Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc})$ ($I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc})$	Both Types MMBT5550 MMBT5551	V _{CE(sat)}	- - -	0.15 0.25 0.20	Vdc
Base – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}$, $I_B = 1.0 \text{ mAdc}$) ($I_C = 50 \text{ mAdc}$, $I_B = 5.0 \text{ mAdc}$)	Both Types MMBT5550 MMBT5551	V _{BE(sat)}	- - -	1.0 1.2 1.0	Vdc
Collector Emitter Cut–off $(V_{CB} = 10 \text{ V})$ $(V_{CB} = 75 \text{ V})$	Both Types	I _{CES}		50 100	nA

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

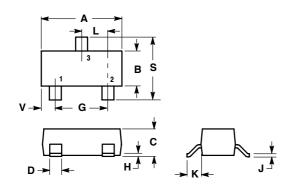
3. Pulse Test: Pulse Width = 300 μ s, Duty Cycle = 2.0%.





PACKAGE DIMENSIONS

SOT-23-3 (TO-236) CASE 318-08 **ISSUE AK**



- NOTES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

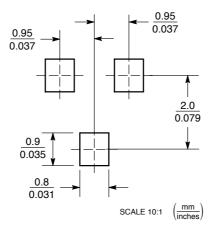
	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.1102	0.1197	2.80	3.04	
В	0.0472	0.0551	1.20	1.40	
С	0.0350	0.0440	0.89	1.11	
D	0.0150	0.0200	0.37	0.50	
G	0.0701	0.0807	1.78	2.04	
н	0.0005	0.0040	0.013	0.100	
J	0.0034	0.0070	0.085	0.177	
ĸ	0.0140	0.0285	0.35	0.69	
L	0.0350	0.0401	0.89	1.02	
S	0.0830	0.1039	2.10	2.64	
V	0.0177	0.0236	0.45	0.60	

STYLE 6:

PIN 1. BASE 2. EMITTER

3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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MMBT5550LT1/D